

Low Power Design Using PIC16/17

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INTRODUCTION

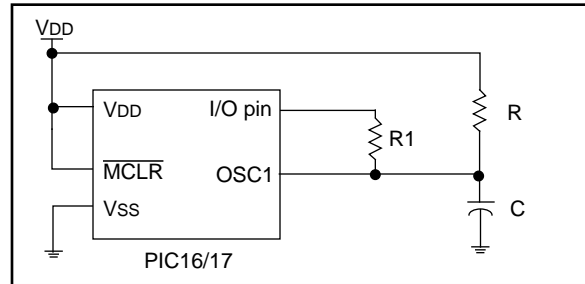
Power consumption is an important element in designing a system, particularly in today's battery powered world. The PIC16/17 family of devices has been designed to give the user a low-cost, low-power, and high performance solution to this problem. For the application to operate at the lowest possible power, the designer must ensure that the PIC16/17 devices are properly configured. This application note describes some design techniques to lower current consumption, some battery design considerations, and suggestions to assist the designer in resolving power consumption problems.

DESIGN TECHNIQUES

Many techniques are used to reduce power consumption in the PIC16/17 devices. The most commonly used methods are SLEEP Mode or external events. These modes are the best way to reduce I_{pd} in a system. The PIC16/17 device can periodically wake-up from Sleep using the Watchdog Timer or external interrupt, execute code and then go back into SLEEP Mode. In SLEEP Mode the oscillator is shut off, which causes the PIC16/17 device to consume very little current. Typical I_{pd} current in most PIC16/17 devices is on the order of a few microamps.

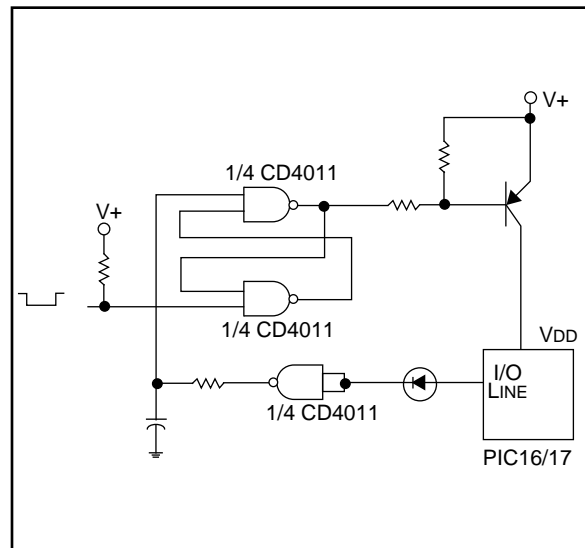
In cases where the PIC16/17 uses an RC oscillator but cannot use SLEEP Mode, another technique is used to lower power consumption. An I/O pin can remove a parallel resistance from the oscillator resistor while waiting for an event to occur. This would slow down the internal clock frequency, by increasing the resistance, and thus reduce I_{pd} . Once an event occurs the resistor can be switched in and the PIC16/17 device can process the event at full speed. Figure 1 shows how to implement this technique. The resistor R1 would be used to increase the clock frequency by making the I/O pin an output and setting it to VDD.

FIGURE 1: USING AN EXTERNAL RESISTOR TO LOWER POWER IN RC MODE



External events can be used to control the power to PIC16/17 devices. For these cases, the Watchdog Timer can be disabled to further reduce current consumption. Figure 2 shows an example circuit that uses an external event to latch power on for the PIC16/17 device. Once the device has finished executing code, it disables power by resetting the latch. The latching circuit uses a low-power 4000 series CMOS quad chip which consumes a typical of 10 μA of current. The measured value of current consumption for the complete circuit with the PIC16/17 powered-down was 1 nA. Current consumption for a PIC16/17 in SLEEP Mode is typically 1 μA .

FIGURE 2: EXTERNAL EVENT POWER CONTROL CIRCUIT



AN606

Power consumption is dependent on the oscillator frequency of the system. The device must operate fast enough to interface with external circuitry, yet slow enough to conserve power. The designer must account for oscillator start-up time, external circuitry initialization, and code execution time when calculating device power consumption. Table 1 shows various frequency oscillators, oscillator modes and the average current consumption of each mode. A PIC16C54 was used to collect data for Table 1 and the code is shown in Example 1. A current profile for a PIC16C54 in RC oscillator mode running at 261 kHz is shown in Figure 3. Figure 4 shows a current profile for a

PIC16C54 in XT mode running at 1 MHz. The current profile includes three regions: power-up, active, and sleep. The power-up region is defined as the time the PIC16/17 device is in Power-On Reset and/or Oscillator Start-up Time. The active region is the time that the PIC16/17 device is executing code and the sleep region is the time the device is in SLEEP Mode. When using a 32.768 kHz crystal in LP oscillator mode, the designer must check that the oscillator has stabilized during the Power-On Reset. Otherwise, the device may not come out of reset properly.

TABLE 1: OSCILLATOR MODES

Osc. Type	Frequency	Osc. Mode	Power-up Region Current, Time	Active Region Current, Time	Sleep Region Current, Time
Resistor / Capacitor	261 kHz	RC	51.2 μ A, 17.5 ms	396 μ A, 12.8 ms	0.32 μ A, 140 ms
Resistor / Capacitor	1.13 MHz	RC	61.4 μ A, 17.5 ms	810 μ A, 2.5 ms	0.3 μ A, 140 ms
Crystal	32.768 kHz	LP	51.2 μ A, 19 ms	23.5 μ A, 93 ms	0.3 μ A, 140 ms
Crystal	50 kHz	LP	61.4 μ A, 16 ms	39.4 μ A, 48.5 ms	0.28 μ A, 140 ms
Crystal	1 MHz	XT	92 μ A, 17.5 ms	443 μ A, 3 ms	0.35 μ A, 140 ms
Crystal	8 MHz	HS	123 μ A, 18 ms	2.11 mA, 250 μ s	0.3 μ A, 140 ms
Resonator	455 kHz	XT	38.4 μ A, 17.3 ms	421 μ A, 7 ms	0.34 μ A, 140 ms
Resonator	8 MHz	HS	143 μ A, 18 ms	2.5 mA, 250 μ s	0.29 μ A, 140 ms

EXAMPLE 1: CURRENT PROFILE CODE

```

TITLE "Current Profiling Program"
LIST P=16C54, F=INHX8M
INCLUDE "C:\PICMASTR\P16C5X.INC"
;*****
;*****
;;      This program initializes the PIC16C54, delays for 256 counts, then goes
;      to sleep. The WDT wakes up the PIC16C54.
;*****
;*****
;Define General Purpose register locations
      LSB      EQU 0x10      ;delay control register
      Reset Vector
      ORG 0
START
      MOVLW    0x0B          ;WDT Prescaler of 1:8
      OPTION
      CLRF     PORTA        ;clear PORTA
      CLRF     PORTB        ;clear PORTB
      CLRW     ;make PORTA and PORTB pins outputs
      TRIS    PORTA
      TRIS    PORTB
      CLRF    LSB
LOOP   DECFSZ   LSB,1
      GOTO    LOOP
      SLEEP   ;go to sleep
      END

```

FIGURE 3: CURRENT PROFILE (261 kHz RC MODE)

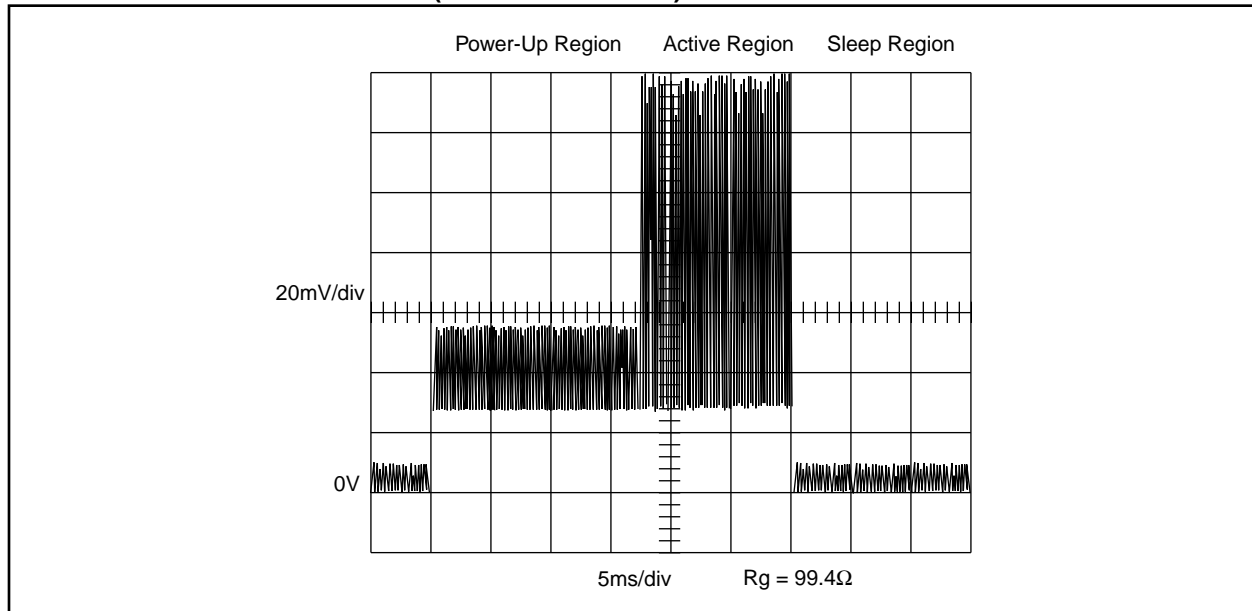
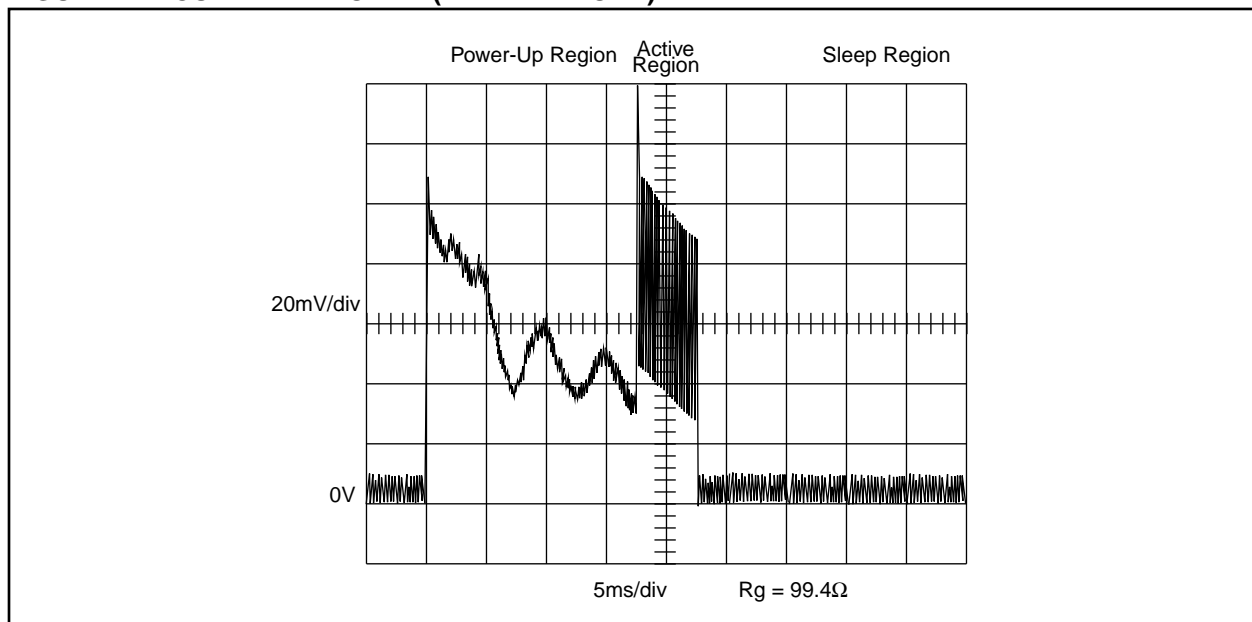


FIGURE 4: CURRENT PROFILE (1 MHz XT MODE)



Designing a system for lower supply voltages, typically 3V, is another method to reduce IPD. This type of design is best utilized in a battery powered system where current consumption is very low. A wide range of devices from op-amps and Analog-to-Digital (A/D) converters to CMOS logic products are being manufactured for low voltage operation. This gives the designer the flexibility to design a low voltage system with the same type of components that are available for a 5V design. Refer to the PIC16/17 device data sheets for IPD vs. VDD data.

Since any I/O pin can source or sink up to 20 mA, the PIC16/17 devices can provide power to other components. Simply connect the VDD pin of an external

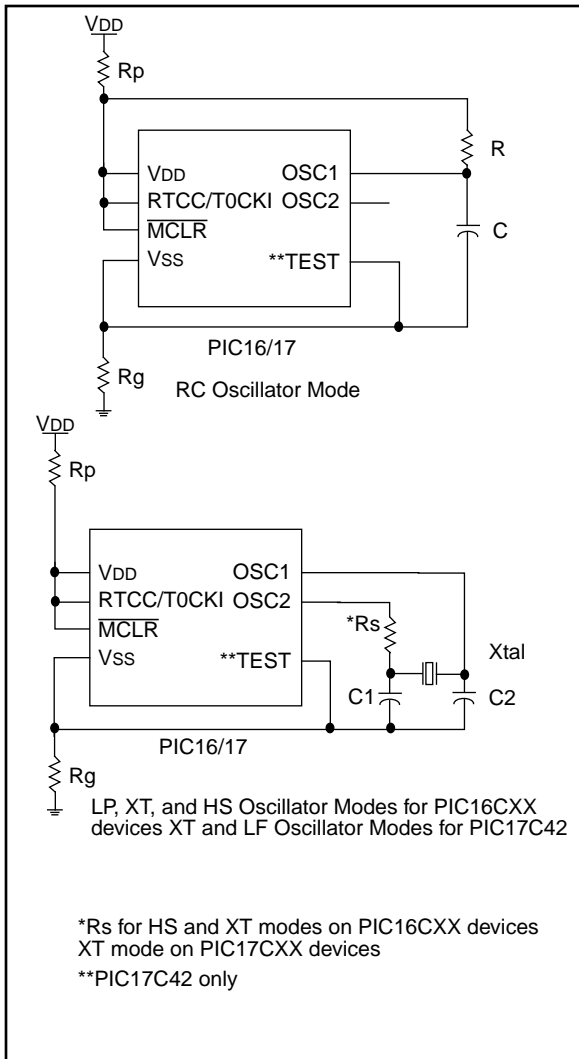
component to an I/O pin. Currently, most of the op-amps, A/D converters, and other devices manufactured today are low-power and can be powered by this technique. This provides the ability to turn off power to sections of the system during periods of inactivity.

Temperature will effect the current consumption of the PIC16/17 devices in different ways. Typically devices will consume more current at extreme temperatures and batteries will have less available current at those same temperatures. PIC16/17 devices will exhibit higher I_{pd} currents at high temperatures. Refer to the PIC16/17 device data sheets for IPD vs. Temperature data.

TROUBLESHOOTING IPD

The first step in troubleshooting IPD problems is to measure the IPD that the circuit is consuming. Circuits to measure IPD for all oscillator modes are shown in Figure 5 for PIC16/17 devices. The resistor R_p is used to measure the amount of current entering the VDD pin when resistor R_g is shorted. The resistor R_g is used to measure the amount of current leaving the VSS pin when resistor R_p is shorted. The value of R_p and R_g should be approximately 100Ω for all oscillator modes. The two values of current should be approximately the same when the PIC16/17 is operating at the lowest possible power. If you find that the values of IPD measured from both configurations are not equivalent or are higher than the specifications, the following suggestions should help to find the source of extra current.

FIGURE 5: CIRCUITS TO MEASURE IPD FOR PIC16/17 DEVICES



Basically, if I_p is not equal to I_g , then an I/O pin is either sourcing ($I_p > I_g$) current or sinking ($I_p < I_g$) current.

- Is the \overline{MCLR} pin tied to VDD? Is the rate of rise of VDD slower than 0.05 V/ms? Does VDD start at VSS then rise? These conditions will not guarantee that the chip will come out of reset and function properly. Some of the circuits on PIC16/17 devices will start operating at lower voltage levels than other circuits. See Application Note AN522 "Power-Up Considerations" in the Microchip *Embedded Control Handbook*.
- Are all inputs being driven to VSS or VDD? If any input is not driven to either VSS or VDD, it will cause switching currents in the digital (i.e., flashing) input buffers. The exceptions are the oscillator pins and any pin configured as an analog input. During Power-on Reset or Oscillator Start-up time, pins that are floating may cause increased current consumption.
- All unused I/O pins should be configured as outputs and set high or low. This ensures that switching currents will not occur due to a floating input.
- Is the TMR0 (RTCC) pin pulled to VSS or VDD? The TMR0 pin of PIC16C5X devices should be tied to VSS or VDD for the lowest possible current consumption.
- If an analog voltage is present at a pin, is that pin configured as an analog input? If an analog voltage is present at a pin configured as a digital input, the digital input buffers devices will consume more current due to switching currents.
- Are all on-chip peripherals turned off? Any on-chip peripheral that can operate with an external clock source, such as the A/D converter or asynchronous timers, will consume extra current.
- Are you using the PORTB internal pull-up resistors? If so and if any PORTB I/O pin is driving or receiving a zero, the additional current from these resistors must be considered in the overall current consumption.
- Is the Power-Up Timer being used? This will add additional current drain during power-up.
- If the currents measured at the R_p and R_g resistors are not the same, then current is being sourced or sunk by an I/O pin. Make sure that all I/O pins that are driving external circuitry are switched to a low power state. For instance, an I/O pin that is driving an LED should be switched to a state where the LED is off.
- Is the window of a JW package device covered? Light will affect the current consumption of a JW package device with the window left uncovered.

IPD Analysis Using A Random Sample

The Microchip *1994 Microchip Data Book* specifies the typical Ipd current for a PIC16C5X part at 4 μ A and the maximum Ipd current at 12 μ A. These values are valid at a VDD voltage of 3V and a temperature range of 0°C to 70°C with the Watchdog Timer enabled. A control group of fifty PIC16C54's were randomly selected with pre-production and production samples. Ipd tests were run on the group for a voltage range of 2.5V to 6.5V and for a temperature range of 0°C to 70°C. Table 2 compares the median and maximum values obtained by the Ipd tests to the typical and maximum values in the data book. The Ipd test data and the data book values are based on VDD = 3.0V, Watchdog Timer Enabled, and a temperature range of 0°C to 70°C.

The values in the data book are obtained from devices in which the manufacturing process has been skewed to various extremes. This should produce devices which function close to the minimum and maximum operating ranges for each parameter shown in the data book. The typical values obtained in the data book are actually the mean value of characterization data at a temperature of 25°C. The minimum and maximum values shown in the data book are the mean value of the characterization data at the worst case temperature, plus or minus three times the standard deviation. Statistically this means that 99.5% of all devices will operate at or below the typical value and much less than the maximum value.

TABLE 2: Ipd COMPARISON OF CONTROL GROUP vs. DATA BOOK VALUES

Source	Typical or Median Ipd	Maximum
Control Group	2.349 μ A	3.048 μ A
1994 Microchip Data Book	4 μ A	12 μ A

BATTERY DESIGN

When designing a system to use batteries, the designer must consider the maximum current consumption, operating voltage range, size and weight constraints, operating temperature range, and the frequency of operation. Once the system design is finished, the designer must again ask some questions that will define what type of battery to use. What is the operating voltage range? What is the current drain rate? What are the size constraints? How long will the system be used? What type of battery costs can be tolerated? What range of temperatures will the system be operated?

It is difficult to state a rule of thumb for selecting batteries because there are many variables to consider. For example, operating voltages vary from one battery type to another. Lithium cells typically provide 3.0V while Nickel-Cadmium cells provide 1.2V. On the other hand, Lithium cells can withstand minimal discharge rates while Nickel-Cadmium can provide up to 30A of current. A designer must consider all characteristics of each battery type when making a selection. Appendix B contains a simple explanation of batteries, a characteristic table for some common battery types, and discharge curves for the common batteries.

It is very important when doing a low power design to correctly estimate the required capacity of the power source. At this point, the designer should be able to estimate the operating voltage, current drain rates and how long the system is supposed to operate. To explain how to estimate the required capacity of a system, we will use the first entry from Table 1 using an RC oscillator set at 261 kHz. Figure 3 shows the current profile for this entry. It can be seen that the profile has a period of 170.3 ms with a 17.5 ms power-up region, a 12.8 ms active region, and a 140 ms sleep region. Assuming that the system will be required to operate for six months, we can now calculate the capacity required to power this system. Example 2 will illustrate the procedure. If a system does not have a periodic current profile, then the percentages obtained in step 1 of Example 2 will have to be estimated.

EXAMPLE 2: CAPACITY CALCULATION

- Calculate the percentage of time spent in power-up, active, and sleep regions.
 - power-up**
 $(17.5 \text{ ms} / 170.3 \text{ ms}) \times 100 = 10.3\%$
 - active**
 $(12.8 \text{ ms} / 170.3 \text{ ms}) \times 100 = 7.5\%$
 - sleep**
 $(140 \text{ ms} / 170.3 \text{ ms}) \times 100 = 82.2\%$
- Calculate the number of hours in 6 months.
 - 6 months
 - $\times (30 \text{ days} / \text{month})$
 - $\times (24 \text{ hours} / \text{day}) = 4320 \text{ hours}$
- Using the number of hours, percentages, and currents calculate the capacity for each period of time
 - power-up**
 $4320 \text{ hours} \times 10.3\% \times 51.2 \mu\text{A} = 22.8 \text{ mAh}$
 - active**
 $4320 \text{ hours} \times 7.5\% \times 396 \mu\text{A} = 128.3 \text{ mAh}$
 - sleep**
 $4320 \text{ hours} \times 82.2\% \times 0.32 \mu\text{A} = 1.14 \text{ mAh}$
- Sum the capacities of each period
 - $22.8 \text{ mAh} + 128.3 \text{ mAh} + 1.14 \text{ mAh} = 152.2 \text{ mAh}$

The capacity required to operate the circuit for six months is 152.2 mAh. Example 2 does not take into consideration temperature effects or leakage currents that are associated with batteries. The load resistance of a battery is affected by temperature which in turn changes the available voltage and current; however, the self discharge rate is higher.

EXAMPLE DESIGN

A PIC16C54 with an LP oscillator of 32.768 kHz is used in this design. A Linear Technology low-power 12-bit A/D converter samples a temperature sensor. This data is transmitted via an LED at 300 baud to a receiver. The A/D converter, op-amp, and temperature sensor are powered from an I/O pin on the PIC16C54. The Watchdog Timer is enabled to periodically wake the system up from Sleep and take a sample. Figure 6 shows the schematic for the example design and Appendix A contains the source code.

This circuit has two operating modes, active and sleep. There was not a distinct power-up region in this design. In the circuit with the peripheral chips powered directly from the battery, the example design consumed 8mA of current in the active mode and 6.5 mA in SLEEP Mode. With the peripheral chips powered from an I/O pin of the PIC16C54, the example design consumed 4 mA of current in the active mode and 0.5 μA in SLEEP Mode. The advantage of using an I/O pin to provide power to

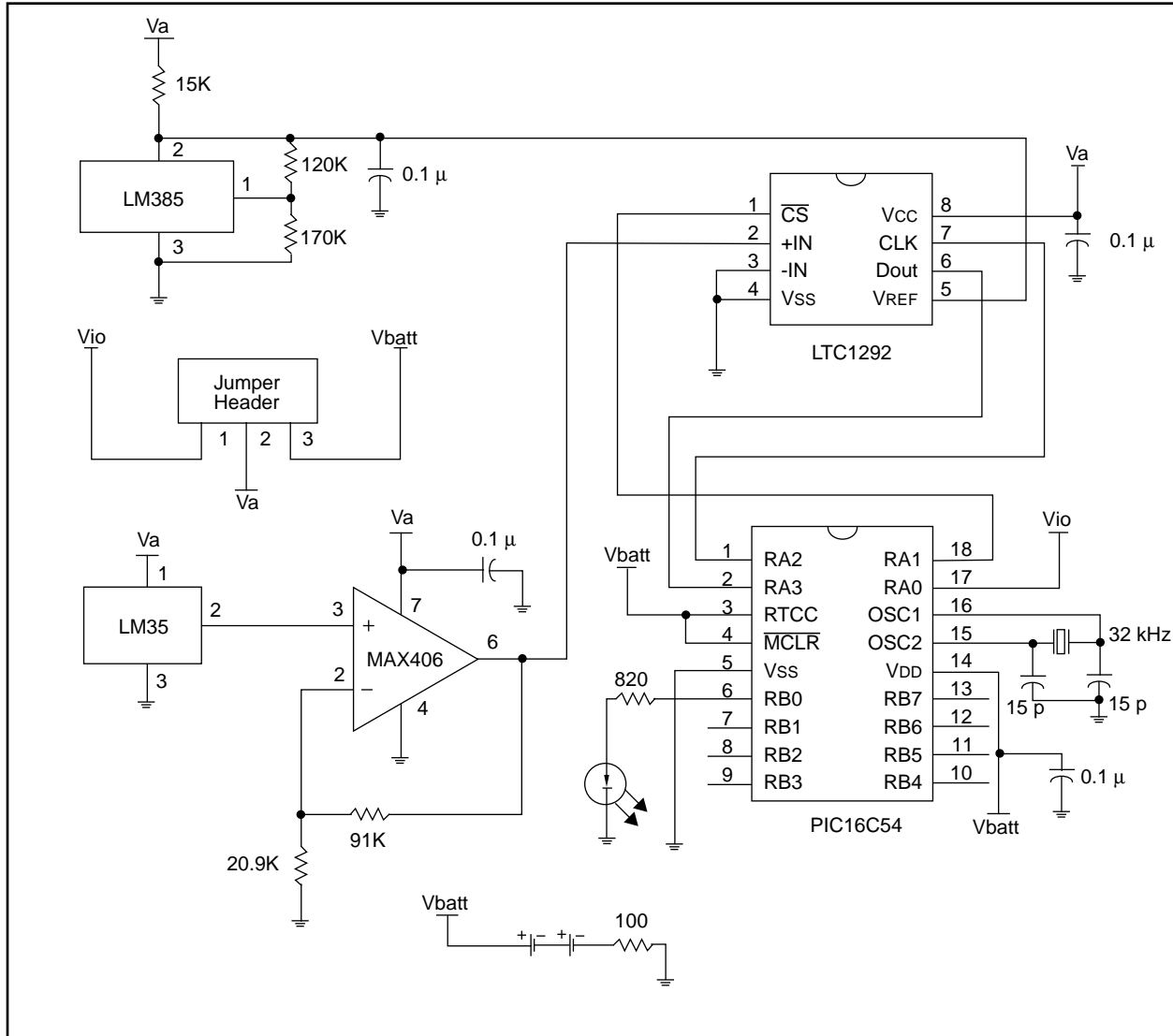
peripherals can be seen in a calculation of the capacity required to operate the circuit for one month. Example 3 details the two capacity calculations.

EXAMPLE 3: CAPACITY CALCULATION FOR THE EXAMPLE DESIGN

- Calculate the percentage of time spent in the active and SLEEP Modes.
 - active - battery power**
 $(210 \text{ ms} / 2.61 \text{ s}) \times 100 = 8\%$
 - sleep - battery power**
 $(2.4 \text{ s} / 2.61 \text{ s}) \times 100 = 92\%$
 - active - I/O power**
 $(188 \text{ ms} / 2.638 \text{ s}) \times 100 = 7.1\%$
 - sleep - I/O power**
 $(2.45 \text{ s} / 2.638 \text{ s}) \times 100 = 92.9\%$
- Calculate the number of hours in 1 month.
 - 1 month
 - $\times (30 \text{ days} / \text{month})$
 - $\times (24 \text{ hours} / \text{day})$
 - $= 720 \text{ hours}$
- Using the number of hours, percentages and currents calculate the capacity for each period of time.
 - active - battery power**
 $720 \text{ hours} \times 8\% \times 8 \text{ mA} = 461 \text{ mAh}$
 - sleep - battery power**
 $720 \text{ hours} \times 92\% \times 6.5 \text{ mA} = 4306 \text{ mAh}$
 - active - I/O power**
 $720 \text{ hours} \times 7.1\% \times 4 \text{ mA} = 205 \text{ mAh}$
 - sleep - I/O power**
 $720 \text{ hours} \times 92.9\% \times 0.5 \mu\text{A} = 0.4 \text{ mAh}$
- Sum the capacities of each period.
 - battery power**
 $461 \text{ mAh} + 4306 \text{ mAh} = 4767 \text{ mAh}$
 - I/O power**
 $205 \text{ mAh} + 0.4 \text{ mAh} = 206 \text{ mAh}$

The capacity required to operate this circuit for one month can be reduced by a factor of twenty just by powering the peripheral components from an I/O pin. The example design will use two Panasonic® BR2325 Lithium batteries in series to provide power to the circuit. This results in a V_{batt} of 6V and a capacity of 165 mAh. Using the estimation process, the circuit should function for approximately 24 days. The actual time of operation was 24.2 days with the system running in an ambient temperature of 22°C.

FIGURE 6: EXAMPLE DESIGN SCHEMATIC



SUMMARY

This application note has described some of the methods used to lower IPD and reduce overall system current consumption. Some obvious methods such as SLEEP Mode and low voltage design were given. Techniques such as powering components from I/O pins and oscillator mode and frequency selection can also be important in reducing IPD and overall system current. Some suggestions for troubleshooting IPD problems were presented. Finally, some considerations for designing a battery powered system were offered.

Please check the Microchip BBS for the latest version of the source code. For BBS access information, see Section 6, Microchip Bulletin Board Service information, page 6-3.

APPENDIX A: EXAMPLE DESIGN CODE

```

MPASM 01.02.05 Released      LOWPWR.ASM      1-9-1995   13:2:42      PAGE 1
Ipd/Battery Apnote Example Design
LOC OBJECT CODE      LINE SOURCE TEXT
VALUE

0001      TITLE "Ipd/Battery Apnote Example Design"
0002      LIST P=16C54, F=INHX8M
0003
0004      INCLUDE "C:\PICMASTR\PI6C5X.INC"
0002 ; PI6C5X.INC Standard Header File, Version 0.1      Microchip Technology, Inc.
0004
0005
0006 ;*****
0007 ;*****
0008 ;
0009 ;      Filename:      lowpwr.asm
0010 ;      REVISION:      9 Jan 95
0011 ;
0012 ;*****
0013 ;
0014 ;      This program initializes the PIC, takes a sample, and outputs the
0015 ;      value to PORTB pin 0 (the LED), and then goes to Sleep. The
0016 ;      Watchdog Timer wakes the device up from Sleep. PORTA pin 0 is used
0017 ;      to control power to peripherals.
0018 ;
0019 ;*****
0020 ;*****
0021
0022 ;      Define variable registers
0023      MSB      EQU      0x10
0024      LSB      EQU      0x11
0025      DELAY_CNT      EQU      0x12
0026      SHIFT      EQU      0x13
0027      COUNT      EQU      0x14
0028
0029 ;      Reset Vector
0030      ORG      0x1FFF
0031      GOTO      START
0032
0033 ;      Start of main code
0010
0011
0012
0013
0014

01FF 0A00

```



```

0000
0000 0C2F
0001 0002
0002 0C02
0003 0025
0004 0066
0005 0C08
0006 0005
0007 0040
0008 0006
0009 0071
000A 0070

000B 0004
000C 0911
000D 0004
000E 0948
000F 0004
0010 0003

0011
0011 0505
0012 0943
0013 0C0B
0014 0034
0015 0C08
0016 0033
0017 0000
0018 0425
0019 0000
001A 0545
001B 0000
001C 0445
001D 0000
001E 0545
001F 0000
0020 0445
0021 0000

0034 0000
0035
0036 ;*****
0037 ; Main routine which initializes the PIC, and has main loop.
0038 ;*****
0039 START
0040 MOVW 0x2F ;1:128 WDT PRESCALAR
0041 OPTION ;RA1 SET HIGH
0042 MOVW 0x02 ;ALL PINS SET TO Vss
0043 MOVWF PORTA ;RA3-DATA INPUT
0044 CLRF PORTB ;RA0-POWER, RA1-CS, RA2-CLOCK OUTPUTS
0045 MOVW 0x08 ;PORTB ALL OUTPUTS, RBO-LED OUTPUT
0046 TRIS PORTA ;CLEAR A/D RESULT REGISTERS
0047 CLRW ;
0048 TRIS PORTB ;
0049 CLRF LSB ;
0050 CLRF MSB ;
0051
0052 CLRWDI
0053 CALL SAMPLE ;GET SAMPLE FROM A/D
0054 CLRWDI
0055 CALL OUTPUT ;OUTPUT SAMPLE TO LED AT 300 BAUD
0056 CLRWDI
0057 SLEEP
0058
0059
0060 ;*****
0061 ; Main routine for retrieving a sample from the A/D.
0062 ;*****
0063 SAMPLE
0064 BSF PORTA,0 ;TURN POWER ON TO PERIPHERALS
0065 CALL DELAY ;WAIT FOR PERIPHERALS TO STABILIZE
0066 MOVW 0x0B ;DATA COUNTER, 12 BIT A/D
0067 MOVWF COUNT
0068 MOVW 0x08 ;SET SHIFT REGISTER
0069 MOVWF SHIFT
0070 NOP
0071 BCF PORTA,1 ;ENABLE A/D
0072 NOP
0073 BSF PORTA,2 ;1ST CLOCK RISE
0074 NOP
0075 BCF PORTA,2 ;1ST CLOCK FALL
0076 NOP
0077 BSF PORTA,2 ;NULL BIT CLOCK RISE
0078 NOP
0079 BCF PORTA,2 ;NULL BIT CLOCK FALL
0080 NOP

```

```

0022 0933          CALL          ;READ DATA BIT
0023 0000          NOP
0024 0545          BSF          PORTA, 2      ;BIT CLOCK RISE
0025 0000          NOP
0026 0445          BCF          PORTA, 2      ;BIT CLOCK FALL
0027 0000          NOP
0028 02F4          DECFSZ      COUNT, F      ;CHECK LOOP COUNTER
0029 0A22          GOTO        LOOP
002A 0933          CALL          ;READ LAST BIT
002B 0000          NOP
002C 0545          BSF          PORTA, 2      ;SET CLOCK
002D 0000          NOP
002E 0525          BSF          PORTA, 1      ;SET CS
002F 0000          NOP
0030 0445          BCF          PORTA, 2      ;CLEAR CLOCK
0031 0405          BCF          PORTA, 0      ;POWER DOWN PERIPHERALS
0032 0800          RETURN

0033
0033 0004          CLRWDI
0034 0774          BTFSS      COUNT, 3      ;CHECK IF AT BIT 8 - 11
0035 0A3B          GOTO        RLOW         ;GOTO BITS 0 - 7
0036 0765          BTFSS      PORTA, 3      ;CHECK IF DATA IS CLEAR
0037 0A3F          GOTO        REND         ;GOTO EXIT
0038 0213          MOVF        SHIFT, W     ;ADD A ONE TO MSB IN THE CORRECT
0039 01F0          ADDWF      MSB, F       ;BIT POSITION
003A 0A3F          GOTO        REND
003B 0765          BTFSS      PORTA, 3      ;ADD A ONE TO LSB IN THE CORRECT
003C 0A3F          GOTO        REND         ;BIT POSITION
003D 0213          MOVF        SHIFT, W     ;SHIFT
003E 01F1          ADDWF      LSB, F       ;SHIFT
003F 0333          RRF         SHIFT, F     ;IF ONE IS IN THE CARRY
0040 0603          BTFSC      STATUS, C      ;SHIFT AGAIN
0041 0333          RRF         SHIFT, F
0042 0800          RETURN

0043
0043 0004          CLRWDI          ;RESET WATCHDOG TIMER
0044 0072          CLR         DELAY_CNT
0045 02F2          DECFSZ      DELAY_CNT, F

```

```

0046 0A45      GOTO    DLOOPL
0047 0800      RETURN
0128
0129
0130
0131
0132 ; *****
0133 ; Output sample to LED at 300 baud.
0134 ; *****
0135 OUTPUT
0136      MOVLM  0x08      ; SHIFT 8 MSB BITS OUT
0137      MOVWF  COUNT
0138
0139 MSBOUT  RLF      MSB,F      ; SHIFT LSB INTO CARRY
0140      BTFSZ  STATUS,C      ; IF CARRY IS SET
0141      GOTO   MSBCLR
0142      BSF   PORTB,0      ; SET PORTB,0
0143      CALL  BAUD
0144      GOTO  MSBCHK      ; CHECK FOR ALL 8 BITS TO BE SENT
0145 MSBCLR  BCF   PORTB,0      ; OTHERWISE CLEAR PORTB,0
0146      NOP
0147      NOP
0148      CALL  BAUD
0149 MSBCHK  DECFSZ COUNT      ; CHECK FOR ALL 8 BITS TO BE SENT
0150      GOTO  MSBOUT
0151
0152      MOVLM  0x08      ; SHIFT 8 LSB BITS OUT
0153      MOVWF  COUNT
0154
0155 LSBOUT  RLF      LSB,F      ; SHIFT LSB INTO CARRY
0156      BTFSZ  STATUS,C      ; IF CARRY IS SET
0157      GOTO   LSBCLR
0158      BSF   PORTB,0      ; SET PORTB,0
0159      CALL  BAUD
0160      GOTO  LSBCHK      ; CHECK FOR 8 BITS TO BE SENT
0161 LSBCLR  BCF   PORTB,0      ; OTHERWISE CLEAR PORTB,0
0162      NOP
0163      NOP
0164      CALL  BAUD
0165 LSBCHK  DECFSZ COUNT      ; CHECK FOR 8 BITS TO BE SENT
0166      GOTO  LSBOUT
0167      BCF   PORTB,0      ; CLEAR PORTB,0
0168      CLRF  LSB
0169      CLRF  MSB
0170      RETURN
0171
0172 ; *****
0173 ; Delay loop for sending data to the LED at 300 baud.
0174 ; *****

```

```
0068      0000
0068 0000
0069 0000
006A 0000
006B 0000
006C 0000
006D 0000
006E 0000
006F 0000
0070 0000
0071 0000
0072 0000
0073 0000
0074 0000
0075 0800

0175 BAUD
0176      NOP
0177      NOP
0178      NOP
0179      NOP
0180      NOP
0181      NOP
0182      NOP
0183      NOP
0184      NOP
0185      NOP
0186      NOP
0187      NOP
0188      NOP
0189      RETURN
0190      END
0191
0192
0193
```

MEMORY USAGE MAP ('X' = Used, '-' = Unused)

```
0000 : XXXXXXXXXXXXXXXXXXXX XXXXXXXXXXXXXXXXXXXX XXXXXXXXXXXXXXXXXXXX XXXXXXXXXXXXXXXXXXXX
0040 : XXXXXXXXXXXXXXXXXXXX XXXXXXXXXXXXXXXXXXXX XXXXXXXXXXXXXXXXXXXX XXXXXXXXXXXXXXXXXXXX
0180 : -----
01C0 : -----X
```

All other memory blocks unused.

```
Errors : 0
Warnings : 0
Messages : 0
```

APPENDIX B: BATTERY DESCRIPTIONS

Presently there are two types of batteries that are manufactured, primary and secondary. Primary batteries are those that must be thrown away once their energy has been expended. Low current drain, short duty cycles, and remote operation favor primary batteries such as Carbon Zinc and Alkaline. Secondary batteries can be recharged once they have exhausted their energy. High current drain or extended usage favors secondary batteries especially when the cost of replacement of disposable batteries is not feasible. Secondary batteries include Nickel-Cadmium and Nickel Metal Hydride.

A battery may be discharged by different means depending on the type of load. The type of load will have a significant effect on the life of the battery. The typical modes of discharge are constant resistance, constant current, and constant power. Constant resistance is when the load maintains a constant resistance throughout the discharge cycle. Constant current is the mode where the load draws the same current during discharge. Finally, constant power is defined as the current during a discharge increases as the battery voltage decreases.

The constant resistance mode results in the capacity of the battery being drained at a rapid and excessive rate, resulting in a short life. This is caused by the current during discharge following the drop in battery voltage. As a result, the levels of current and power during discharge are in excess of the minimum required.

The constant current mode has lower current and power throughout the discharge cycle than the constant resistance mode. The average current drain on the battery is lower and the discharge time to the end-voltage is longer.

The constant power discharge mode has the lowest average current drain and therefore has the longest life. During discharge, the current is lowest at the beginning of the cycle and increases as the battery voltage drops. Under this mode the battery can be discharged below its end voltage, because the current is increased as the voltage drops. The constant power mode provides the most uniform performance throughout the life of the battery and has the most efficient use of the energy in the battery.

The nominal voltage is the no-load voltage of the battery, the operating voltage is the battery voltage with a load, and the end-of-life voltage is the voltage when the battery has expended its energy. Energy Density is used to describe the amount of energy per unit of volume or mass (Wh/kg or Wh/l). Generally, energy density decreases with decreasing battery size within a particular type of battery. Most batteries are rated by an amp-hour (Ah) or milliamp-hour (mAh) rating. This rating is based on a unit of charge, not energy. A 1-amp current corresponds to the movement of 1 coulomb (C) of charge past a given point in 1 second (s). Table B-1 lists some typical characteristics of the most common types of batteries.

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TABLE B-1: TYPICAL BATTERY CHARACTERISTICS

	Carbon Zinc	Alkaline	Nickel Cadmium	Lithium	Nickel Metal Hydride	Zinc Air	Silver Oxide
Cell Voltage							
Nominal	1.5	1.5	1.2	3.0	1.2	1.4	1.6
Operating	1.25-1.15	1.25-1.15	1.25-1.00	2.5-3.0	1.25-1.0	1.35-1.1	1.5
End of life	0.8	0.9	0.9	1.75	0.9	0.9	0.9
Operating Temperature	-5°C to 45°C	-20°C to 55°C	-40°C to 70°C	-30°C to 70°C	-20°C to 50°C	0°C to 45°C	-20°C to 50°C
Energy Density (Wh/kg)	70	85	30	300	55	300	100
Capacity	60mAh to 18Ah	30mAh to 45Ah	150mAh to 4Ah	35mAh to 4Ah	500mAh to 5Ah	50mAh to 520mAh	15mAh to 210mAh
Advantages		High capacity, good low temp	good low temp, good high rate discharge	good low and high temp, good high rate discharge, long shelf life	better capacity than Nicad for same size	high energy density, good shelf life	good low temp, good shelf life
Limitations	Low energy density, poor low temp, poor high rate discharge		poor low rate discharge, disposal hazards	Violent reaction to water		Cannot stop reaction once started	poor high rate discharge
Relative Cost	low	low	medium	high	high	high	high
Type	Primary	Primary	Secondary	Primary	Secondary	Primary	Primary

Typical discharge curves for alkaline, carbon zinc, lithium, nickel cadmium, nickel metal hydride, silver oxide, and zinc air are shown in Figure B-1 through Figure B-7. These curves are only typical representations of each battery type and are not specific to any battery manufacturer. Also the load and current drain are different for each type of battery.

FIGURE B-1: ALKALINE DISCHARGE CURVE (16 mA LOAD)

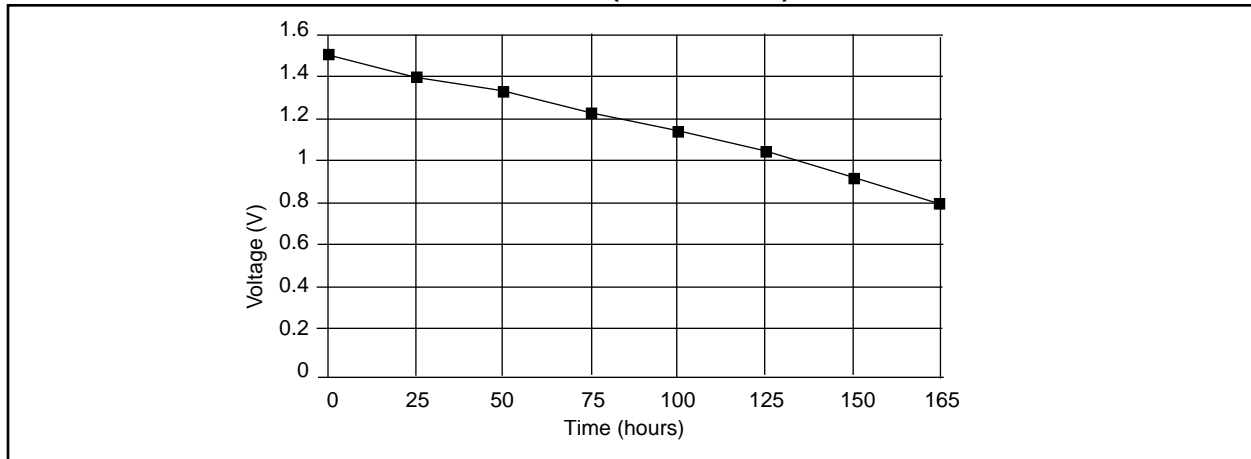


FIGURE B-2: CARBON ZINC DISCHARGE CURVE (16 mA LOAD)

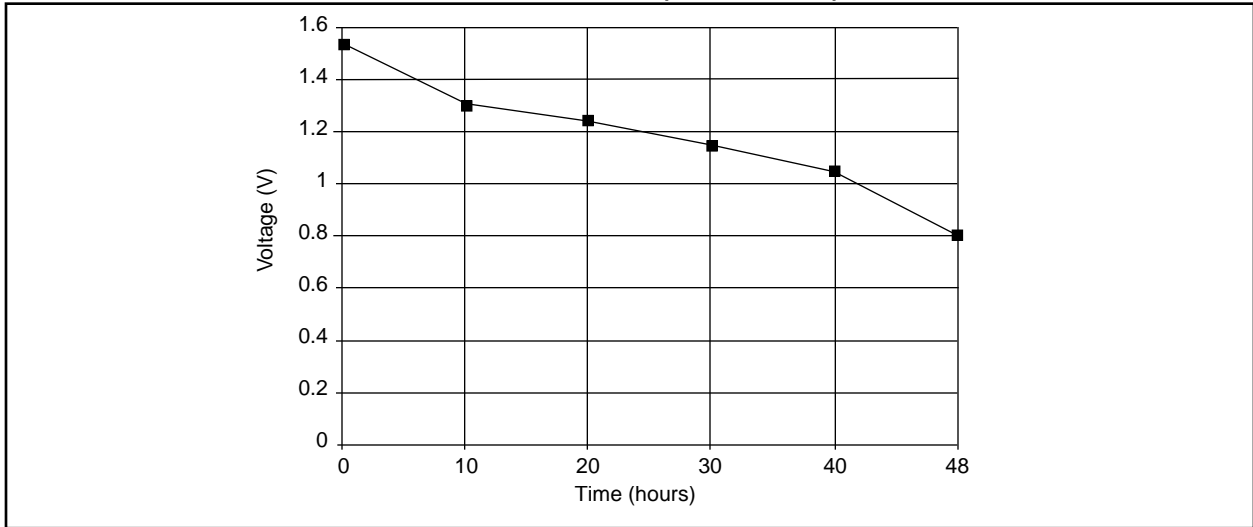


FIGURE B-3: LITHIUM DISCHARGE CURVE (2.8 mA LOAD)

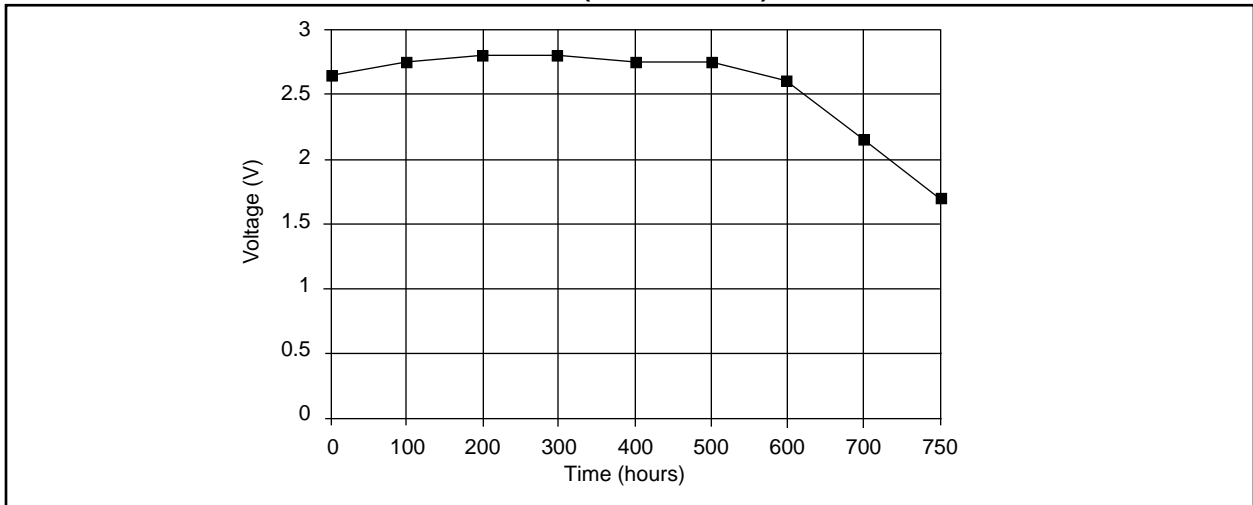
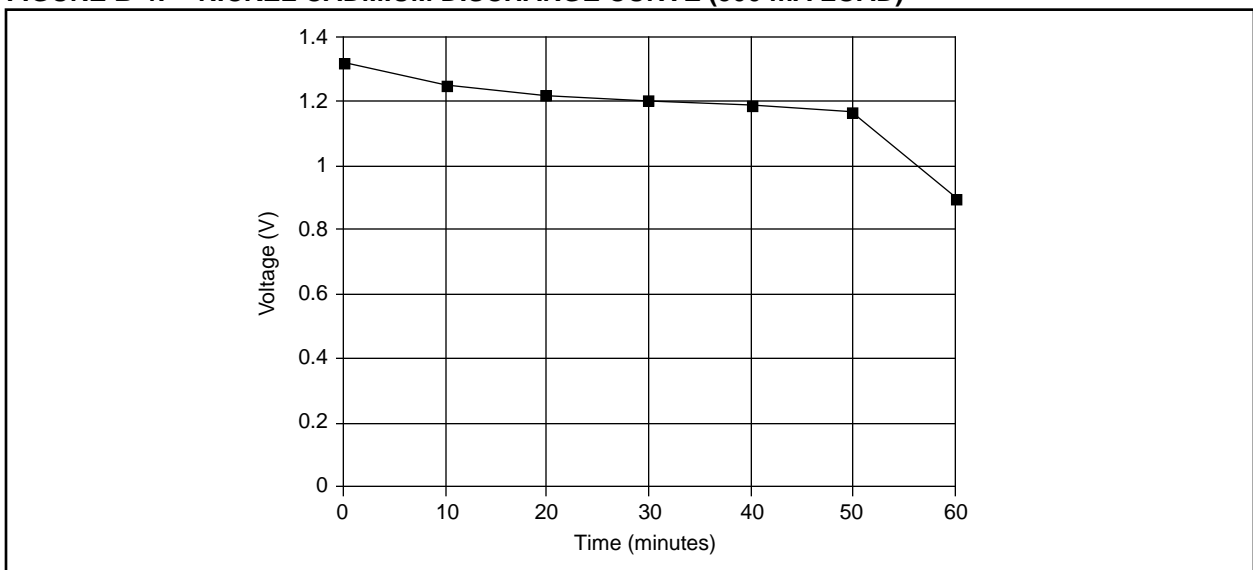


FIGURE B-4: NICKEL CADMIUM DISCHARGE CURVE (500 mA LOAD)



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FIGURE B-5: NICKEL METAL HYDRIDE DISCHARGE CURVE (1500 mA LOAD)

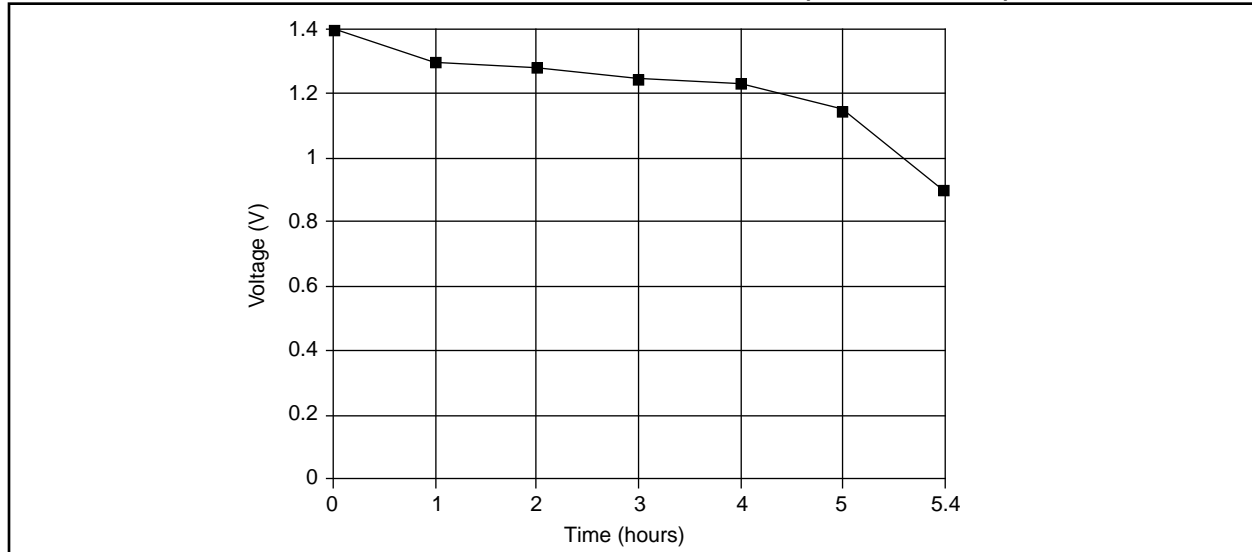


FIGURE B-6: SILVER OXIDE DISCHARGE CURVE (1 mA LOAD)

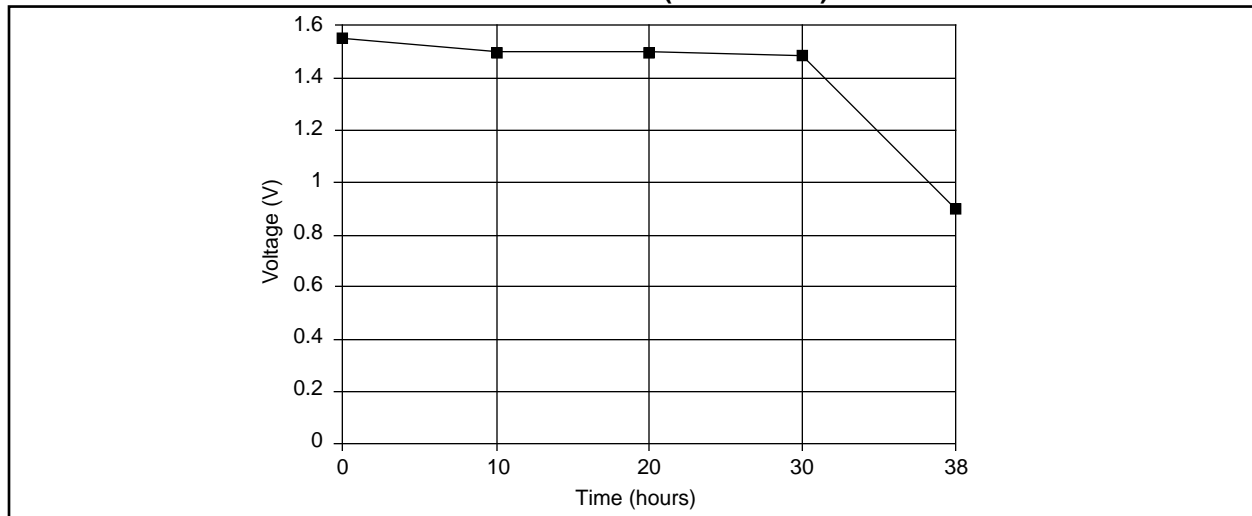
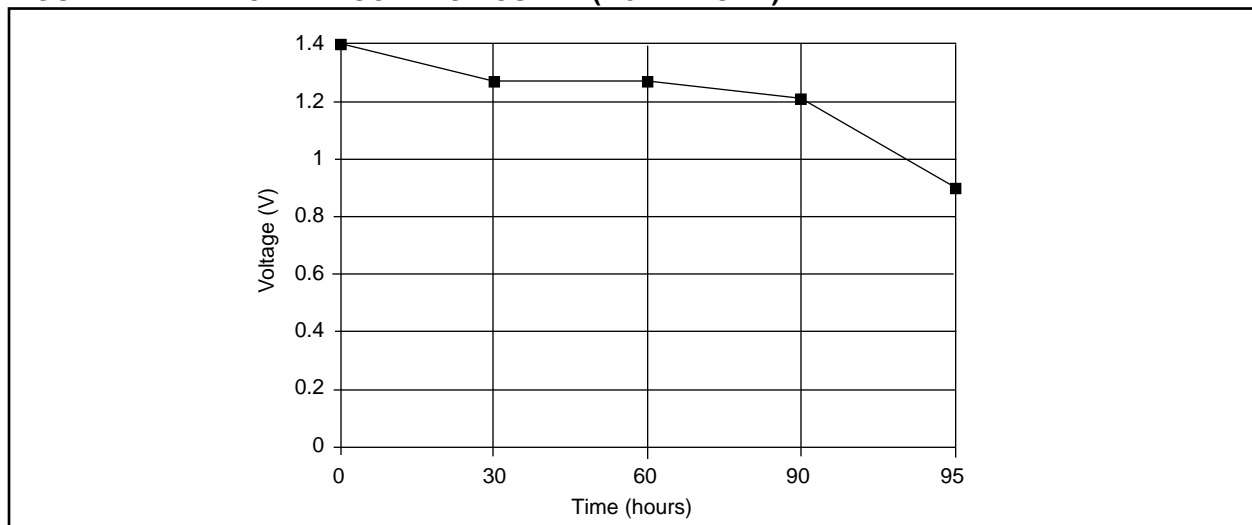


FIGURE B-7: ZINC AIR DISCHARGE CURVE (1.3 mA LOAD)



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